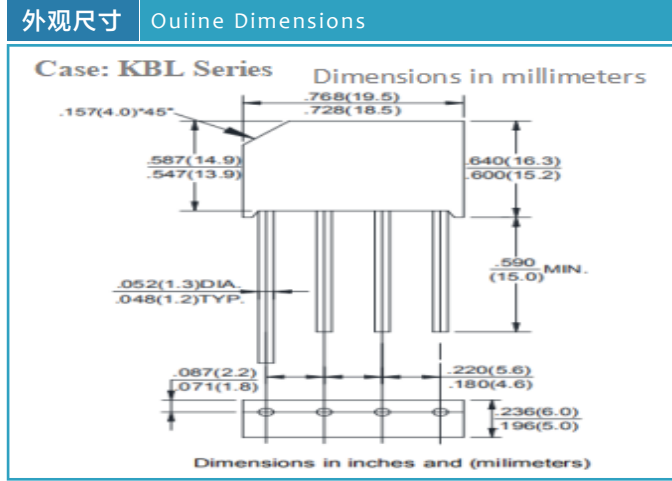
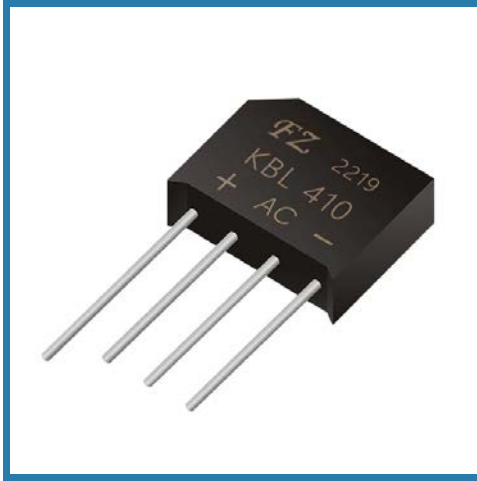


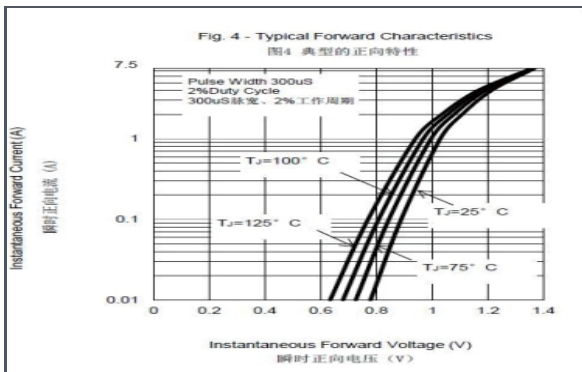
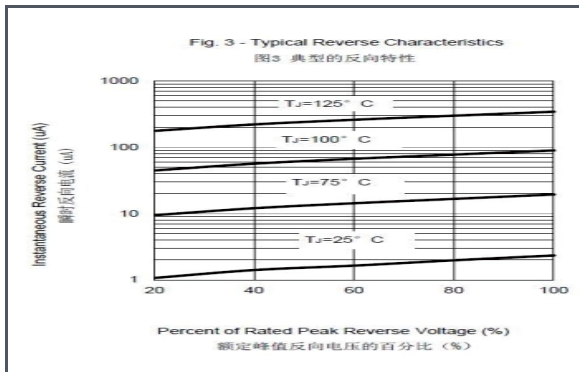
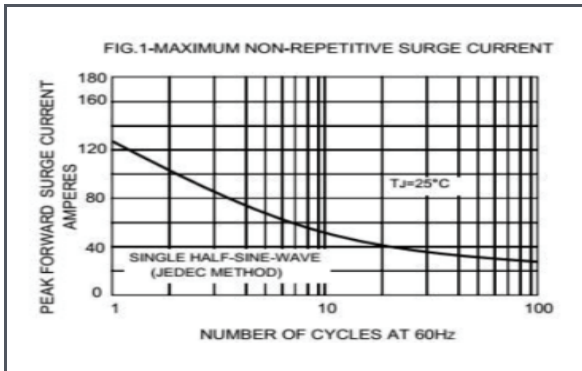
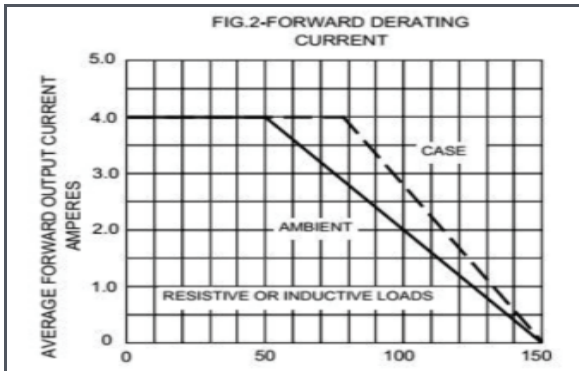
# KBL404 thru KBL410



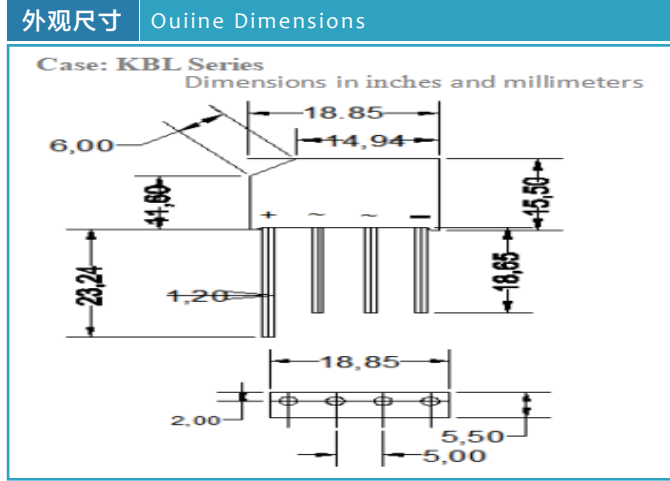
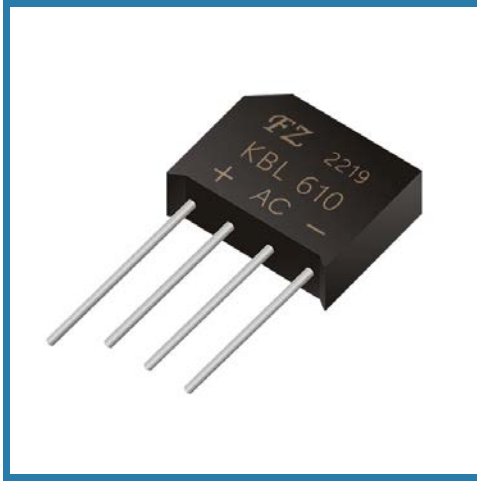
产品特性 Features

- 产品采用GPP玻璃纯化芯片，低反向漏电流，高耐浪涌电流能力，接线端与壳体间绝缘耐压2500V
- 最大反向重复峰值电压:1000V  
Maxmum Recurrent Peak Reverse Voltage
- 平均整流输出电流:4A  
Average Forward Output Rectified Current@
- 正向浪涌电流:125A  
Peak Forward Surge Current 8.3ms Single Half Sine-wave superimposed on rated load
- 反向漏电流  
Maximum DC reverse current at rated DC blocking voltage per leg Ta = 25 °C Ta = 125 °C
- 正向峰值电压:1.1V  
Forward Voltage Per Leg @IFM =4.0A

特性曲线 Characteristics(Typical)



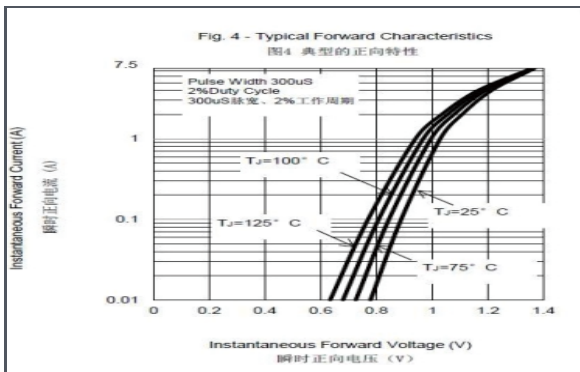
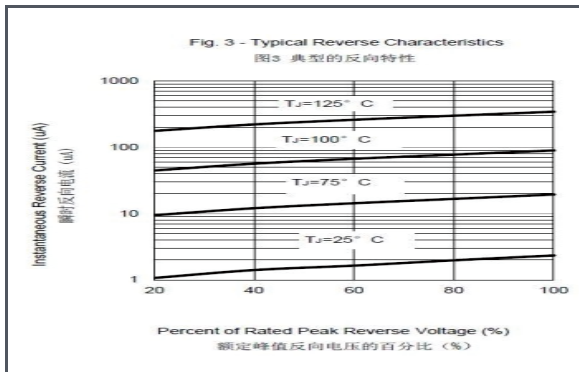
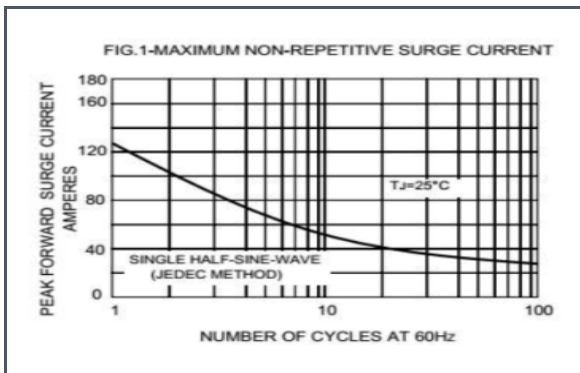
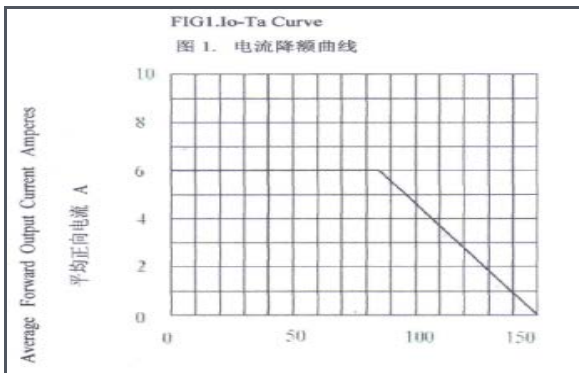
# KBL604 thru KBL610



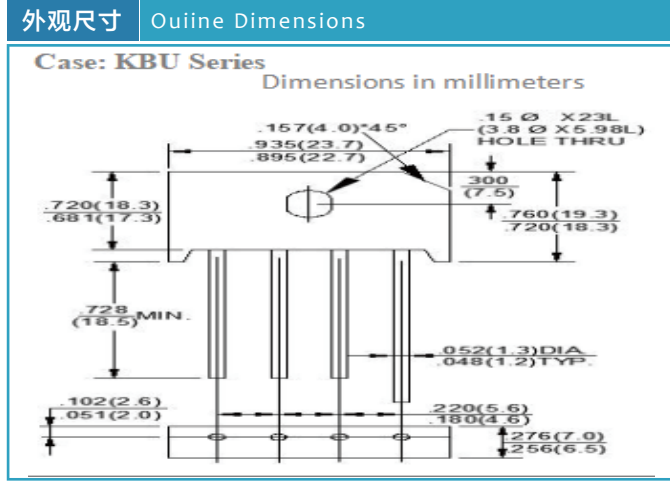
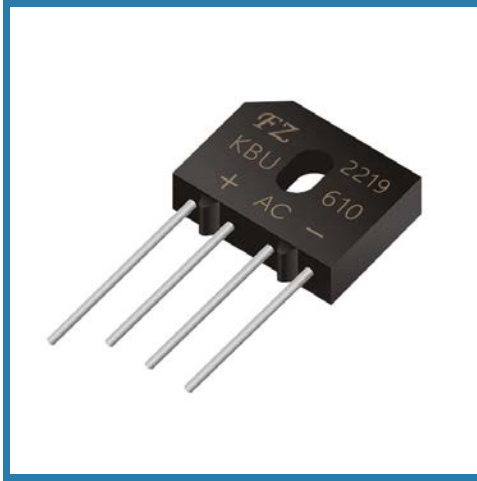
产品特性 Features

- 产品采用GPP玻璃纯化芯片，低反向漏电流，高耐浪涌电流能力，接线端与壳体间绝缘耐压2500V
- 最大反向重复峰值电压:1000V  
Maximum Recurrent Peak Reverse Voltage
- 平均整流输出电流:6A  
Average Forward Output Rectified Current@
- 正向浪涌电流:125A  
Peak Forward Surge Current 8.3ms Single Half Sine-wave superimposed on rated load
- 反向漏电流  
Maximum DC reverse current at rated DC blocking voltage per leg  $T_a = 25^\circ\text{C}$   
 $T_a = 125^\circ\text{C}$
- 正向峰值电压:1.1V  
Forward Voltage Per Leg @IFM =6.0A

特性曲线 Characteristics(Typical)



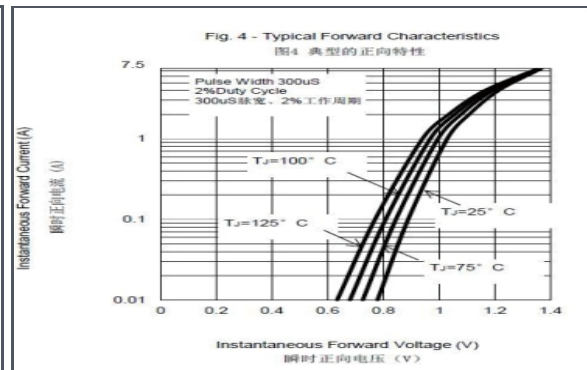
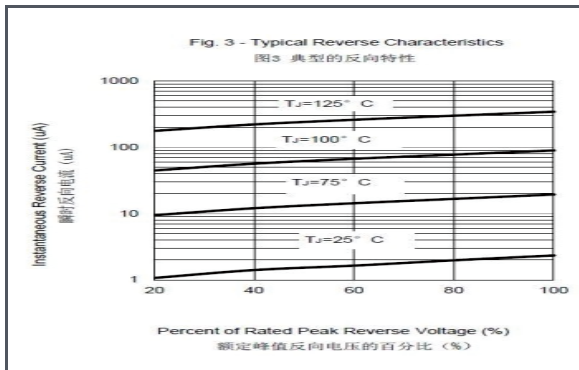
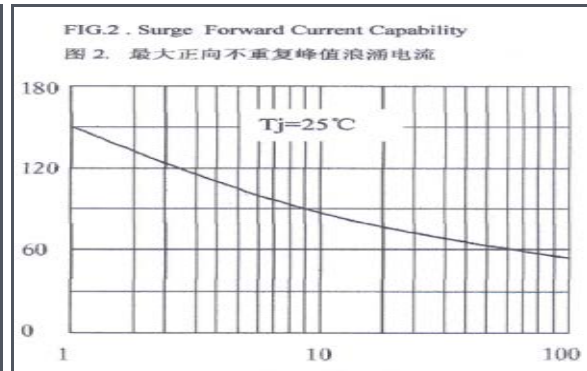
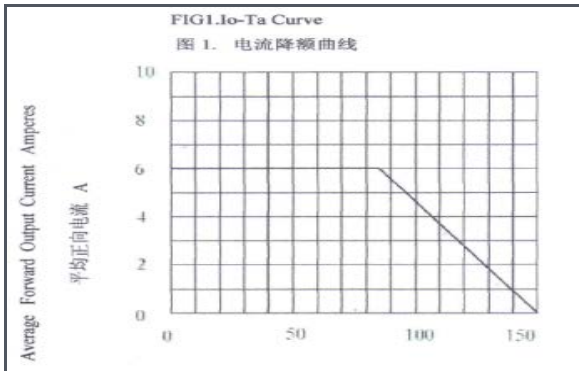
# KBU604 thru KBU610



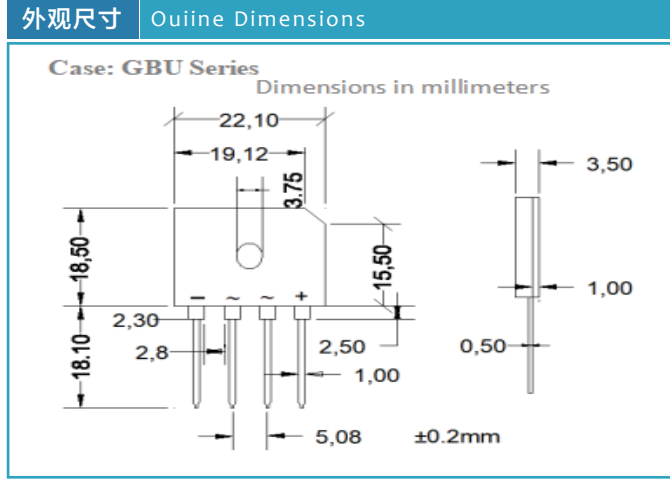
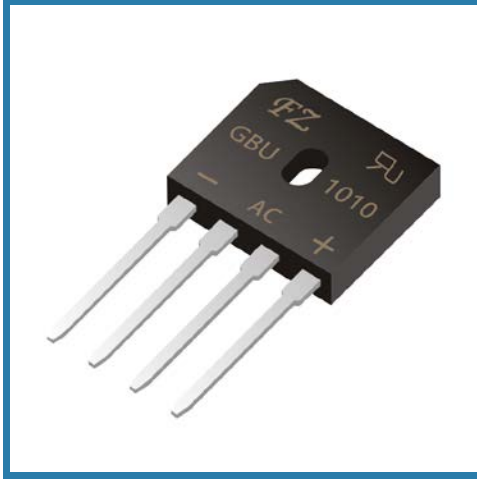
产品特性 Features

- 产品采用GPP玻璃纯化芯片，低反向漏电流，高耐浪涌电流能力，接线端与壳体间绝缘耐压2500V
- 最大反向重复峰值电压:1000V  
Maximum Recurrent Peak Reverse Voltage
- 平均整流输出电流:6A  
Average Forward Output Rectified Current@
- 正向浪涌电流:160A  
Peak Forward Surge Current 8.3ms Single Half Sine-wave superimposed on rated load
- 反向漏电流  
Maximum DC reverse current at rated DC blocking voltage per leg Ta = 25 °C Ta = 125 °C
- 正向峰值电压:1.1V  
Forward Voltage Per Leg @IFM =6.0A

特性曲线 Characteristics(Typical)



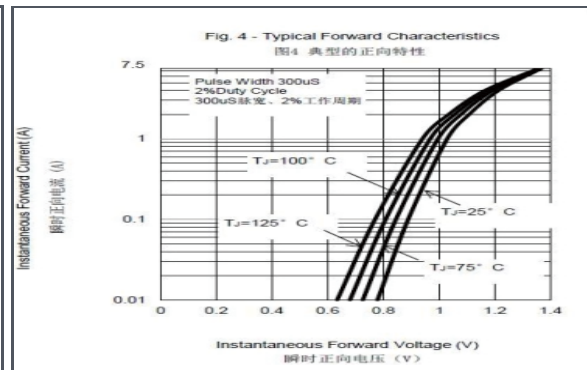
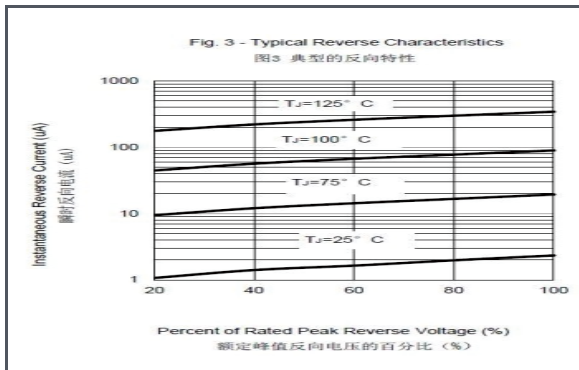
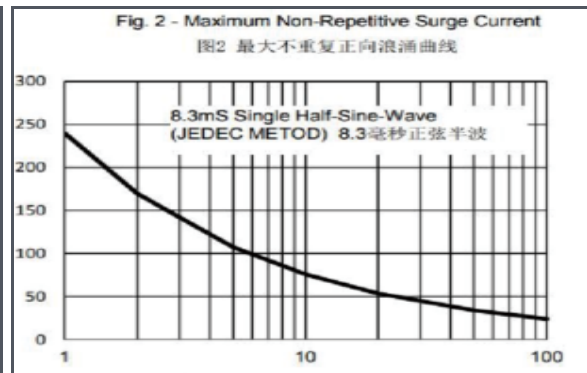
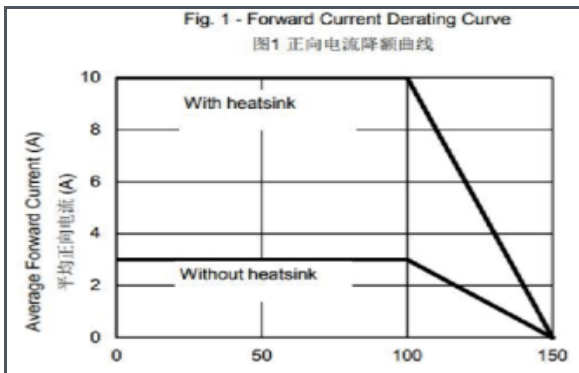
# GBU1004 thru GBU1010



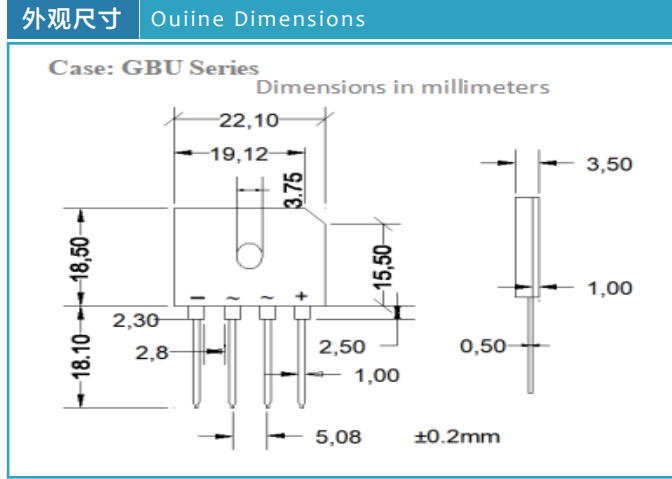
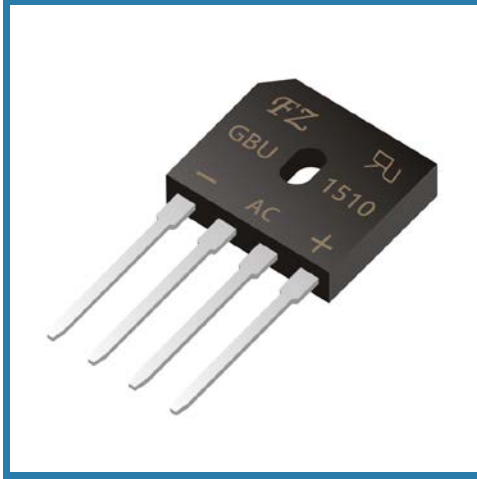
产品特性 Features

- 产品采用GPP玻璃纯化芯片，低反向漏电流  
高耐浪涌电流能力，接线端与壳体间绝缘耐压2500V
- 最大反向重复峰值电压:1000V  
Maximum Recurrent Peak Reverse Voltage
- 平均整流输出电流:10A  
Average Forward Output Rectified Current@
- 正向浪涌电流:220A  
Peak Forward Surge Current 8.3ms Single Half Sine-wave superimposed on rated load
- 反向漏电流  
Maximum DC reverse current at rated DC blocking voltage per leg Ta = 25 °C Ta = 125 °C
- 正向峰值电压:1.1V  
Forward Voltage Per Leg @IFM =10A

特性曲线 Characteristics(Typical)



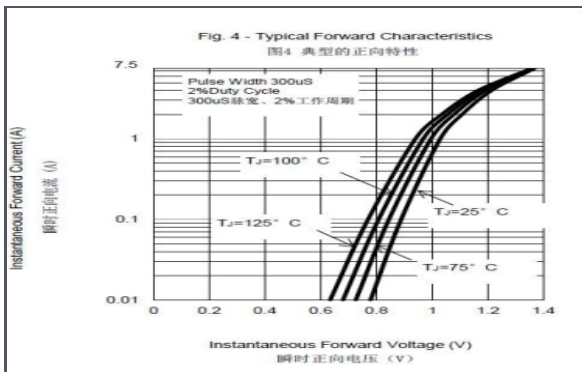
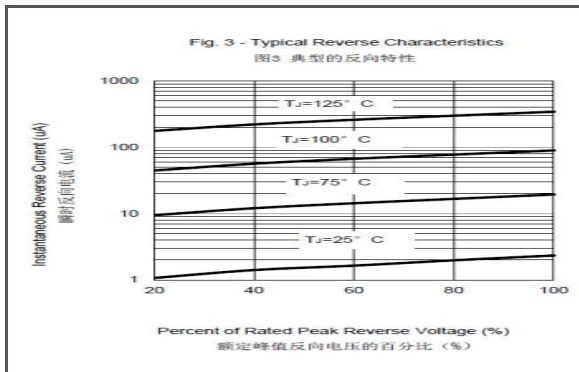
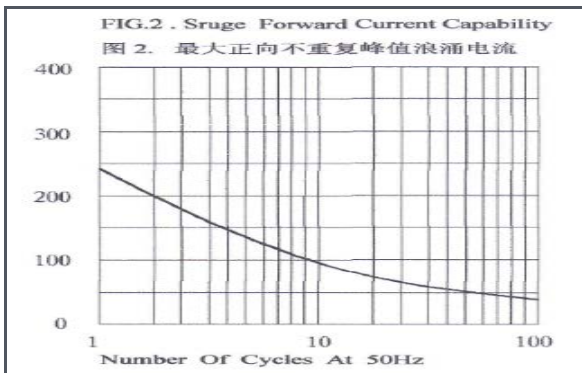
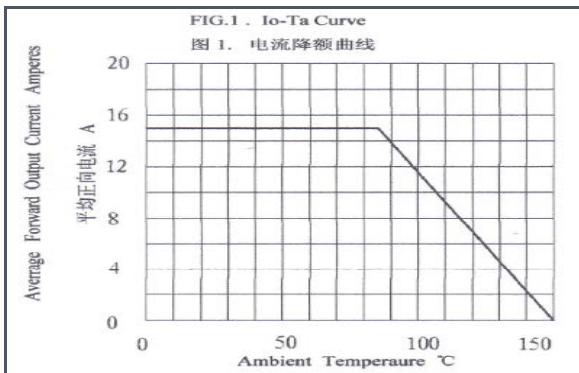
# GBU1504 thru GBU1510



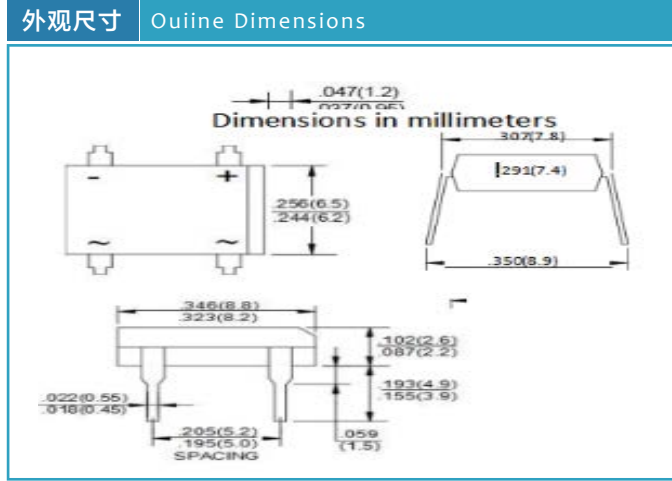
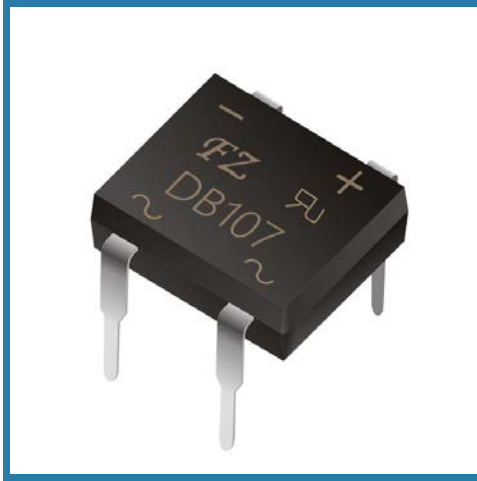
产品特性 Features

- 产品采用GPP玻璃纯化芯片，低反向漏电流  
高耐浪涌电流能力，接线端与壳体间绝缘耐压2500V
- 最大反向重复峰值电压:1000V  
Maximum Recurrent Peak Reverse Voltage
- 平均整流输出电流:15A  
Average Forward Output Rectified Current@
- 正向浪涌电流:240A  
Peak Forward Surge Current 8.3ms Single Half Sine-wave superimposed on rated load
- 反向漏电流  
Maximum DC reverse current at rated DC blocking voltage per leg Ta = 25 °C Ta = 125 °C
- 正向峰值电压:1.1V  
Forward Voltage Per Leg @IFM =15A

特性曲线 Characteristics(Typical)



# DB104 thru DB107



产品特性 Features

- 产品采用GPP玻璃纯化芯片，低反向漏电流，高耐浪涌电流能力，接线端与壳体间绝缘耐压2500V
- 最大反向重复峰值电压:1000V  
Maximum Recurrent Peak Reverse Voltage
- 平均整流输出电流:1A  
Average Forward Output Rectified Current@
- 正向浪涌电流:30A  
Peak Forward Surge Current 8.3ms Single Half Sine-wave superimposed on rated load
- 反向漏电流  
Maximum DC reverse current at rated DC blocking voltage per leg Ta = 25 °C Ta = 125 °C
- 正向峰值电压:1.1V  
Forward Voltage Per Leg @IFM =1A

特性曲线 Characteristics(Typical)

